



IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Applicants: Ting-Wah Wong et al.

Serial No.: 10/081,111

Filed: February 21, 2002

For: Integrated Radio Frequency Circuits

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Art Unit: 2811

Examiner: Ori Nadav

Atty Docket: PSS.0029P7US

Commissioner for Patents
Washington, D.C. 20231

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REPLY TO PAPER NO. 5

Sir:

In response to the office action mailed December 2, 2002, please amend the above-referenced patent application as follows:

In the Claims:

Please amend claim 1 as follows:

1. (Amended) A method comprising:
forming a metal oxide semiconductor radio frequency circuit element over a triple

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biasing a well of said triple well through a resistor.

Please cancel claim 6 without prejudice.

Please amend claim 20 as follows:

20. (Amended) A method comprising:
forming a first metal oxide semiconductor radio frequency circuit element over a
triple well in a substrate;
biasing a first well of said triple well through a first resistor with a first bias
potential;

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Date of Deposit: JANUARY 21, 2003

I hereby certify under 37 CFR 1.8(a) that this correspondence is being deposited with the United States Postal Service as **First Class Mail** with sufficient postage on the date indicated above and is addressed to the Commissioner for Patents, Washington, D.C. 20231.

Ella Sisco

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